

# **SBG2030CT - SBG2045CT**

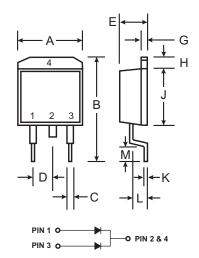
### 20A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 225A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Lead Free Finish/RoHS Compliant (Note 3)

#### **Mechanical Data**

- Case: D<sup>2</sup>PAK
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Bright Tin. Solderable per MIL-STD-202, Method 208
- Ordering Information, Page 2
- Polarity: See Diagram
- Marking: Type Number
- Mounting Position: Any
- Weight: 1.7 grams (approximate)



D <sup>2</sup> PAK						
Dim	Min	Max				
Α	9.65	10.69				
В	14.60	15.88				
С	0.51	1.14				
D	2.29	2.79				
Е	4.37	4.83				
G	1.14	1.40				
Н	1.14	1.40				
J	8.25	9.25				
K	0.30	0.64				
L	2.03	2.92				
М	2.29	2.79				
All Dimensions in mm						

## Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

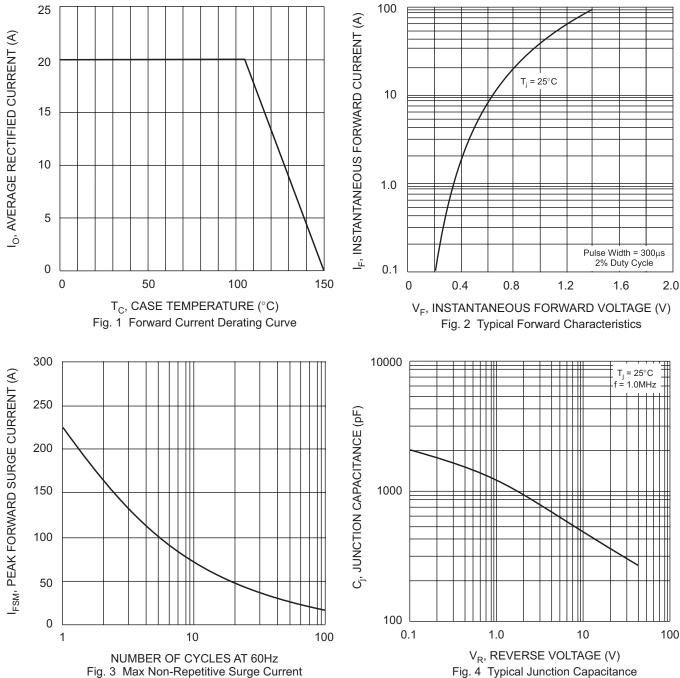
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	SBG 2030CT	SBG 2035CT	SBG 2040CT	SBG 2045CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	35	40	45	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	21	25	28	32	V
Average Rectified Output Current @ $T_C = 105$ °C		lo	20			Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		I <sub>FSM</sub>	225			А	
Forward Voltage, per Element @ I <sub>F</sub> = 10A		V <sub>FM</sub>	0.55			٧	
Peak Reverse Current at Rated DC Blocking Voltage	@ T <sub>j</sub> = 25°C @ T <sub>j</sub> = 100°C	I <sub>RM</sub>			.0		mA
Typical Junction Capacitance (Note 2)		Cj	650			pF	
Typical Thermal Resistance Junction to Case (Note 1)		R <sub>θJC</sub>	2.0			K/W	
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-65 to +150			°C	

Notes:

- 1. Thermal resistance: junction to case mounted on heat sink.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.





## Ordering Information (Note 4)

Device	Packaging	Shipping
SBG2030CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch
SBG2035CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch
SBG2040CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch
SBG2045CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch

Notes: 4. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02007.pdf.



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